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Synthesis, structural, spectroscopic and electric/dielectric studies of a nanocrystalline Ni(II) complex based on [(1,3-diphenyl-1*H*-pyrazol-4-yl) methylene]thiocarbonohydrazide

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A Ni^{2+} nanocomplex based on a heterocyclic ligand containing a pyrazole moiety was developed in this work, and its electric conductivity and dielectric characteristics were studied. The Ni^{2+} nanocomplex with the general formula $[Ni(PyT)_2(H_2O)_2]Cl_2\cdot\frac{1}{2}H_2O$, where PyT=[(1,3-diphenyl-1H-pyrazol-4-yl) methylene]thiocarbonohydrazide, was characterized using various techniques, including elemental and thermal analyses, as well as conductivity, magnetism, TEM, and spectroscopic (FT-IR, UV-Vis and XRD) studies. The results showed that PyT was bonded to the Ni(III) centers via a neutral bidentate ligand, resulting in an octahedral-shaped, thermally stable mononuclear complex. The frequency response of the dielectric properties and ac conductivity was studied in the range from 200 Hz to 6 kHz. Both dielectric constant and dielectric loss decreased with increasing frequency. In addition, the effect of temperature was investigated in the range of 294.1–363.4 K. The ac conductivity increased with increasing temperature in the range of 294.1–333.5 K. The ac conduction is described as correlated barrier hopping between non-intimate valence alternation pairs. Furthermore, the PyT and Ni(PyT) nanocomplex structures were optimized using theoretical calculations and DFT computations.

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1 Introduction

Thiocarbohydrazide derivatives are an important class of compounds with a wide range of applications in the biochemical, pharmaceutical, and industrial domains. The antiviral, antidiabetic, hepatoprotective, antibacterial, and antiproliferative properties of thiocarbohydrazone ligands have been studied. Additionally, because of their flexible coordination ability and hybrid soft-hard donor nature, thiocarbohydrazone ligands easily form metal complexes. Both organic molecules and their metal complexes display a wide range of pharmacological functions, including anticancer, antibacterial, and fungistatic actions. The majority of studies mainly report the preparation and identification of thiocarbohydrazones and their coordinated compounds. The majority of studies mainly report the preparation and identification of thiocarbohydrazones and their coordinated compounds.

Researchers in the field of electronic materials have been constantly examining and refining particular material features according to their usefulness. However, capacitor dielectrics have long been a focus of research among several electronic materials.⁶

Hydrazones have a variety of qualities that are of interest to scientists and useful in everyday life. Some of these properties include thermal endurance, conductivity, and chelate production. This has sped up the development of novel Schiff bases with unique characteristics and the growth of their applications.7-9 In recent years, organic semiconductors have gained popularity in electronics and optoelectronic technologies because of their intriguing electrical and optical properties, 10,11 low cost and ease of making films. Additional energy sublevels are formed in organic molecules when transition metal ions are added. These compounds typically exhibit enhanced charge transfer from ligand to metal or metal to ligand, larger electronic transitions, and intramolecular electron delocalization, resulting in increased electrical properties. Using metal complexes to create electrical and photoelectric devices including diodes, transistors, sensors, photodetectors, and solar cells is one of the most fascinating areas of research for chemists and physicists alike. These are seen as alternatives to traditional semiconductor materials because of their possible usage with flexible substrates, ease of production via continuous printing, broad application scope, and considerable environmental and economic benefits.9

AC conductivity and dielectric behavior studies of materials are important to discover the charge transport mechanism and explain the origin of dielectric losses, which in turn is helpful to determine the presence of defects in these materials and gain

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essential knowledge about the transport processes in the localized states of the bandgap.¹²⁻¹⁴ In addition, it is important to investigate the dielectric behavior of these materials to design passive devices for integrated circuits.^{15,16} In a series of articles, several models have been proposed to explain the electronic structure, ac conduction, and dielectric behavior of materials.^{14,17-23}

This study reports the synthesis and characterization of a novel $Ni(\pi)$ nanocomplex based on [(1,3-diphenyl-1H-pyrazol-4-yl)methylene]thiocarbonohydrazide for electronic applications. TGA-DTG, X-ray diffraction, and optical absorption of this new complex were studied. In addition, the temperature and frequency responses of its ac conductivity and dielectric parameters were investigated. Therefore, this study provides new insights into the properties and behavior of the Ni(PyT) complex, which indicate its potential application in various fields such as materials science, optical technology and the determination of complex characteristics, especially conductivity properties, and that they can be developed further for various optical applications in the future.

2 Experimental

2.1. Chemicals and methods

Analytical grading chemicals were used as starting material. Thiocarbohydrazide, pyrazole, and nickel chloride were purchased from BDH, Analar, or Merck chemicals. Spectroscopic grade solvents, including ethanolic solvent and dimethylformamide (DMF), were purchased commercially and used as received.

At Cairo University's Micro-analytical Central Laboratory, the percentage of H, C, N, and S elements was calculated using a Vario EL Element Analyzer. In addition, complexometric titration was used to detect the percentage of the Ni(II) metal. England's Stuart melting point instrument was employed to determine the melting and decomposition points. For molar conductance, a 10⁻³ M solution of the Ni(II) complex was dissolved in DMF using a Corning conductivity meter (NY 14831 model). Moreover, the electronic spectra of PyT and its Ni(II) complex were measured using 10⁻³ M solutions using a JASCO UV-Vis spectrophotometer (V-550). Using an FT-IR Nicolet IS10 spectrometer, FT-IR spectra (4000-400 cm⁻¹) of PyT and its Ni(II) complex were detected. The effective magnetic moment of the Ni(II) complex (μ_{eff}) was calculated using the relation μ_{eff} = 2.828 (cm T)^{1/2} B.M., where cm is the molar susceptibility corrected for the diamagnetism of all atoms in the compound using Pascal's constants. In addition, a magnetic susceptibility balance from Sherwood Scientific in Cambridge Science Park (England) was used to measure the magnetic susceptibility using the Gouy method. XRD patterns of the produced compounds were captured using a PHILIPS diffractometer with CuK1 radiation ($\lambda = 1.54056 \text{ Å}$, current = 30 mA and accelerating voltage = 40 kV). A transmission electron microscope (TEM, JEM-2100 (JEOL)) working at an accelerating voltage of 200 kV was used for imaging. An RCL Bridge (PM-6304 Fluke & Phillips) was used to measure the loss tangent and capacitance, which were used to determine the dielectric parameters and ac

conductivity of the $Ni(\pi)$ complex sample prepared in the form of a circular disc with a thickness of 0.72 mm. The sample was placed in a furnace using a special holder with two circular electrodes and a temperature controller.

2.2. Synthesis of [(1,3-diphenyl-1*H*-pyrazol-4-yl)methylene] thiocarbonohydrazide (PyT)

[(1,3-Diphenyl-1*H*-pyrazol-4-yl)methylene] thiocarbonohydrazide (**PyT**) was synthesized using a previously reported method.²⁴ ¹H NMR: 4.82 (br, 2H, NH₂), 7.03–7.88 (m, 10H, Ph–H), 8.16 (s, H, CH=N), 9.24 (s, 1H, H-5_{pyrazole}), 9.51 (brs, 1H, CS<u>NH</u>NH₂), 11.34 (brs, 1H, <u>NH</u>CSNHNH₂).

2.3. Synthesis of the Ni(PyT) complex

Ethanolic solutions of nickel chloride and PyT were used in a stoichiometric reaction at a molar ratio of 1:2 to synthesize the Ni(PyT) complex. For 8 hours, the resulting mixture was heated through a reflux system (pH = 5.5). Then, the colored precipitate was filtered and washed multiple times with a 1:1 solution of ethanol and water to remove remnants of unreacted components. The precipitate was finally dried in a suction desiccator, yielding a nearly reddish-brown powder of the Ni(PyT) complex: $[Ni(PyT)_2(H_2O)_2]Cl_2 \cdot \frac{1}{2}H_2O$; yield: 83%; melting point >300 °C; anal. found (calcd) for C₃₄H₃₇N₁₂O_{2.5}S₂Cl₂-Ni: M. wt: (847); %C: 48.41 (48.18); % H: 4.63 (4.40); % N: 20.00 (19.83); % S: 7.61 (7.56); % Ni: 7.11 (6.92); FT-IR (KBr, cm⁻¹): 3410 (ν OH), 3102 (ν NH₂, ν NH), 3054 (ν CH_{arom}), 1597, (ν CH=N), 1540, 755 (νC=N_{pyrazole}), 1156 (νN-N), 1204, 828 (νNH-C=S), 506 (ν M–O), 469 (ν M–N). Molar conductivity ($\Lambda_{\rm m}$): 107 S mol⁻¹ cm²; UV/Vis (DMF) λ_{max} (nm): 348, 405, 592, 883. μ_{eff} (B.M.): 2.7. Scheme 1 provides a representation of the chemical structure of the Ni(PyT) complex.

2.4. DFT calculations

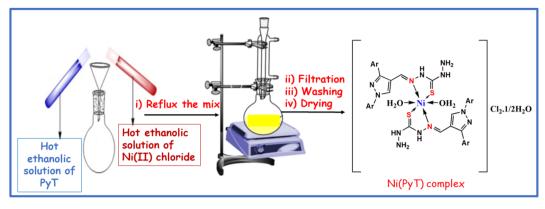
DFT calculations of the **PyT** structure have been reported in our previous research work.²⁵ Herein, DFT calculations of the Ni(**PyT**) nanocomplex were carried out using the Gaussian 09 software.²⁶ The standard base set B3LYB/6-311G(p,d) was used to optimize the geometry. Using Gauss View 5.0.9 software, the optimal structure and HOMO–LUMO of the produced compounds were determined.²⁷

3 Results and discussion

3.1. Characterization of the Ni (PyT) nanocomplex

PyT was reacted directly with Ni(II) ions at a molar ratio of 1:2, producing a pure reddish-brown precipitate of the Ni(**PyT**) complex, which has the general formula of $[Ni(PyT)_2(H_2O)_2]$ $Cl_2 \cdot \frac{1}{2}H_2O$. The powder exhibited no change or decomposition at room temperature, demonstrating excellent stability in the air. However, upon heating to 300 °C, the complex underwent decomposition, which suggests high thermal stability, and as a result, a strong coordination bond between the Ni²⁺ ions and **PyT**. In organic solvents such as acetone, methanol and ethanol, the Ni(**PyT**) complex was weakly soluble. However, the Ni(**PyT**) complex easily dissolved in the solvents DMF and DMSO. The

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Scheme 1 Schematic representation of the Ni(PyT) complex.

elemental examination supported the predicted structure of Ni(PyT) given in Scheme 1. According to the analytical results, the Ni(PyT) complex was formed when Ni^{2+} and PyT were reacted at a stoichiometric ratio of 1:2.

The hypothesized chemical structure of the Ni(PyT) complex is based on analytical data obtained from the thermal gravimetric analysis (TGA). As shown in Fig. 1, the Ni(PyT) complex loses two coordinated water molecules and half a lattice water molecule at 169 °C with an observed weight loss of 5.50% (calcd 5.31%). Then, two molecules of HCl are removed at a higher temperature (250 °C) with a weight loss of 14.00% (calcd 13.91%). The Ni(PyT) complex continues to degrade thereafter from 250 to 433 °C, exhibiting a weight loss of 50.50% (calcd 50.78%), which is attributed to the removal of four molecules of C_6H_6 .

The molar conductance of a 10^{-3} M solution of the Ni(PyT) complex was found to be in a range typical of 1:2 electrolytes at ambient temperature, showing that two anions were present as counter ions outside the coordination sphere.^{28,29}

IR spectral data of **PyT** and the Ni(**PyT**) nanocomplex were compared, and some clear and observable spectral changes were found. In addition, the FT-IR data are used to support the chelation modes of **PyT** with the metal ion. The presence of stretching vibrations of the N-H and C=S groups in the

spectrum of Ni(PyT) confirms the coordination of PyT with the metal ion in neutral form. The shift of the $\nu(NHC=S)$ of PvT (1235, 843 cm⁻¹) to lower wavenumbers (1205, 828 cm⁻¹) in the spectrum of the complex indicates that thioxo sulfur was chelated with the metal ion.30 In addition, the negative shift of the $\nu(CH=N)$ signal from 1617 cm⁻¹ (PyT) to 1597 cm⁻¹ (the Ni(PyT) complex) indicates that the nitrogen of the azomethine group bonded with the metal ion.24,30 Moreover, the 11 cm-1 shift of the $\nu(N-N)$ of **PyT** to lower wavenumbers in the Ni(**PyT**) complex spectrum supports the involvement of azomethine nitrogen in coordination.³⁰ The coordination of the azomethine group is further supported by the presence of a non-ligand band at 469 cm⁻¹ assigned to ν (M-N).^{31,32} The IR spectrum of the Ni(PvT) complex revealed a new band at 3410 cm⁻¹ corresponding to the $\nu(OH)$ group of lattice water. ^{33,34} The emergence of a band at 506 cm⁻¹ corresponding to $\nu(M \leftarrow O)$ in the FT-IR spectrum of the Ni(PyT) complex is another evidence in favour of the above hypothesis.34,35

Therefore, according to the IR analysis, **PyT** functions as a neutral bidentate ligand with indents at azomethine N and thione S.

Fig. 2 represents the XRD patterns of the PyT and Ni(PyT) complex powders. PyT has a crystalline form according to the

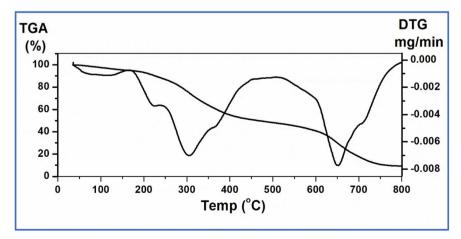


Fig. 1 TGA-DTG curve of the Ni(PyT) nanocomplex.

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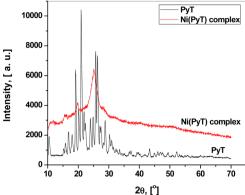


Fig. 2 XRD patterns of PyT and the Ni(PyT) complex.

XRD patterns; however, the Ni(PyT) complex has a fine nanocrystalline nature. The crystallite size L of the Ni(PyT) complex was calculated from the main peak using the Scherer equation $L=0.9\lambda/(\beta\cos\theta)$, where θ is the diffraction angle, and β is the full width at half maximum.³⁶ The calculated crystallite size of the Ni(PyT) complex was about 4.4 nm. The chelation of the metal ion with PyT to form a new complex was confirmed by the differences in diffraction intensity and diffraction angle between PyT and its Ni(PyT) complex.³⁷

The TEM image of the Ni(PyT) complex showed that the Ni(PyT) complex has a rod shape with an average diameter of 48 nm (Fig. 3).

The selected area electron diffraction (SAED) patterns of the Ni(PyT) complex showed good diffraction rings, indicating its crystalline nature (Fig. 4).

As shown in Fig. 5, the UV-Vis electronic spectra of the DMF solutions of **PyT** and its Ni(**PyT**) complex were measured. The absorption spectrum of **PyT** showed one absorption band at 332 nm due to the $n-\pi^*$ transitions within the C=S and C=N

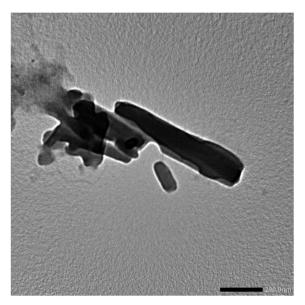


Fig. 3 TEM image of the Ni(PyT) complex.

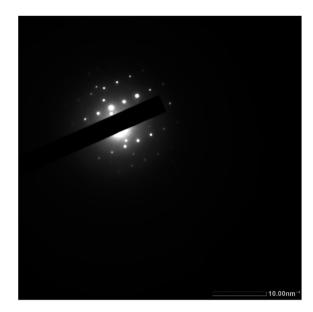


Fig. 4 Electron diffraction pattern image of the Ni(PyT) complex.

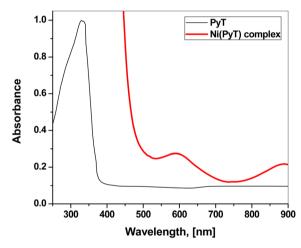


Fig. 5 Absorption spectra of PyT and the Ni(PyT) nanocomplex

groups. The other band that appeared as a shoulder at 370 nm could be attributed to the π – π^* transitions within the aromatic rings. ^{38,39} In the UV-Vis spectrum of Ni(**PyT**), the bands of the intraligand were shifted to a higher wavelength. This behavior implies that the metal ions coordinate with nitrogen and/or sulfur. Moreover, the absorption spectrum of Ni(**PyT**) exhibited bands in the visible region. One band appeared at 592 nm, and the other band appeared as a hump at 890 nm. These bands could be assigned to the ${}^3A_{2g}(F) \rightarrow {}^3T_{1g}(F)$ and ${}^3A_{2g}(P) \rightarrow {}^3T_{1g}(P)$ transitions in the octahedral Ni(II) complex. ^{40,41} Furthermore, the magnetic moment of the Ni(**PyT**) complex was measured, and its value was 2.9 B.M. This result is consistent with the octahedral geometry. ⁴²

3.2. Dielectric properties

Electrical polarization reduces the electric field inside materials by a factor called complex dielectric permittivity ε^* , which is given by the following formula:⁴³⁻⁴⁵

 $\varepsilon^* = \varepsilon_1 - i\varepsilon_2$

where ε_1 and ε_2 are the dielectric constant and dielectric loss, respectively. ε_1 was calculated from the measured capacitance C using the following equation:^{45–47}

$$\varepsilon_1 = \frac{C \cdot d}{\varepsilon_0 A}$$

where A is the effective area, d is the thickness of the sample and ε_0 is the permittivity of the vacuum ($\varepsilon_0=8.85\times 10^{-12}$ F m⁻¹). The response of the dielectric constant to frequency and temperature are shown in Fig. 6(a and b). Clearly, ε_1 decreased with increasing frequency. On the other hand, ε_1 increased with the temperature, reaching its maximum value at 323.5 K at all studied frequencies except for the lowest frequency (200 Hz) for which the maximum value was at 333.5 K. Then, ε_1 decreased with a further increase in temperature.

The dielectric constant shows the ability of a material to store electric charge because it refers to the degree of polarization. 42,44 The high dielectric constant ε_1 of the polar material at low frequencies results from different polarization types (interfacial, orientation, ionic and electronic polarization). 42,48 The dielectric

constant decreases with increasing frequency because the dipoles are unable to rotate rapidly. This decreases the ionic and orientation contributions.⁴⁹ On the other hand, the first increase in temperature facilitates the orientation of the dipoles, leading to an increase in the dielectric constant. The following decrease in ε_1 at the higher temperature range might result from the change in the structure of the complex and the loss of lattice water (Fig. 1).^{44,48}

The dielectric loss ε_2 , which represents the dissipation of energy, was calculated from the measured loss tangent $\tan \delta$ as follows:^{45,46}

$$\varepsilon_2 = \varepsilon_1 \tan \delta$$

The dependence of dielectric loss ε_2 on the frequency and temperature is presented in Fig. 7(a and b). Clearly, the dielectric loss behaved similarly to the dielectric constant in response to frequency and temperature. Fig. 7(a) shows that ε_2 decreased with increasing frequency. Fig. 7(b) shows that ε_2 increased with increasing temperature, reaching a maximum at around 323.5–333.5 K, and then decreased with a further increase in temperature.

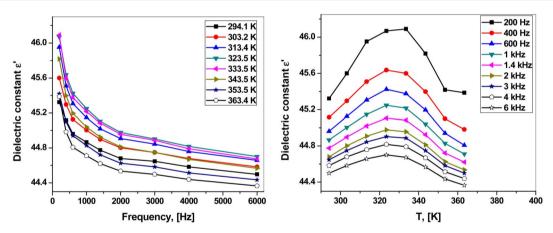


Fig. 6 (a) Frequency dependence of the dielectric constant. (b) Temperature dependence of the dielectric constant.

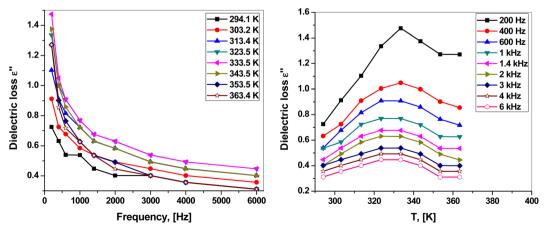


Fig. 7 (a) Frequency dependence of dielectric loss. (b) Temperature dependence of dielectric loss.

At low frequencies, ε_2 has a high value because of different factors such as ion polarization, ion jump, ion vibration, and conduction loss of charge carriers. Some of these sources are lost with increasing frequency, leading to a decrease in dielectric loss.^{42,44}

When a material is placed in an electric field, electrons hop from the donor to acceptor states, forming a dipole for each pair of these sites. 17,18 The relaxation time τ of each dipole depends on the activation energy attributed to a potential barrier. 50 This potential barrier results from the coulombic interaction between the neighboring sites of the dipoles. $^{19-21}$ The dielectric loss ε_2 is related to the frequency of the applied field as follows: 22,44,51,52

$$\varepsilon_2 = \text{constant} \times (2\pi f)^m$$

Fig. 8 shows the plot of $\ln \varepsilon_2$ versus $\ln(2\pi f)$. Clearly, they could be fitted linearly at all temperatures, obeying the previous equation. The frequency exponent m was determined from the slope of the linear fittings. The barrier height $W_{\rm m}$ was calculated at each temperature using the following formula: 51,52

$$W_{\rm m} = -4k_{\rm B}T/m$$

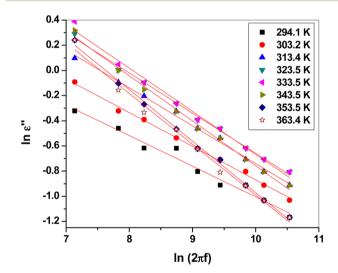


Fig. 8 In ε_2 versus ln($2\pi f$) at different temperatures.

Table 1 Temperature dependence of the potential barrier height

T[K]	$W_{\mathrm{m}}\left[\mathrm{eV}\right]$	
294.1	0.42	
303.2	0.39	
313.4	0.36	
323.5	0.35	
333.5	0.34	
343.5	0.33	
353.5	0.30	
363.4	0.31	

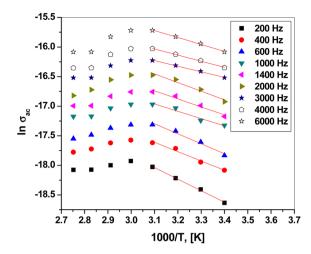


Fig. 9 $\ln \sigma_{\rm ac}$ versus 1000/T at different frequencies.

where $k_{\rm B}$ is the Boltzmann's constant. Table 1 presents the values of barrier height at each temperature. Clearly, $W_{\rm m}$ decreased with increasing temperature.

3.3. AC conductivity

The ac conductivity was determined from the dielectric loss as follows:53-55

$$\sigma_{\rm ac} = \omega \varepsilon_{\rm o} \varepsilon_{\rm 2}$$

Fig. 9 presents the plot of $\ln \sigma_{\rm ac}$ versus 1000/T at different frequencies. Clearly, $\sigma_{\rm ac}$ increased with increasing temperature up to 323.5 K, obeying the Arrhenius relation:^{56–58}

$$\sigma_{\rm ac} = \sigma_{\rm o} \, \exp\!\left(\frac{-\Delta E_{\rm ac}}{k_{\rm B}T}\right)$$

where $\Delta E_{\rm ac}$ is the ac activation energy. The increase in $\sigma_{\rm ac}$ with increasing temperature could be due to the enhanced thermal

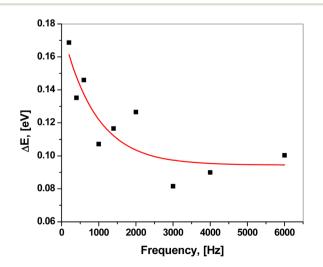


Fig. 10 Frequency dependence of the ac activation energy $\Delta E_{\rm ac}$.

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activation of the electron drift valuatity 59,60 The values of AE

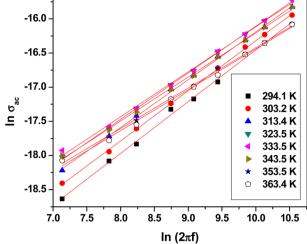


Fig. 11 $\ln \sigma_{ac}$ versus $\ln(2\pi f)$ at different temperatures.

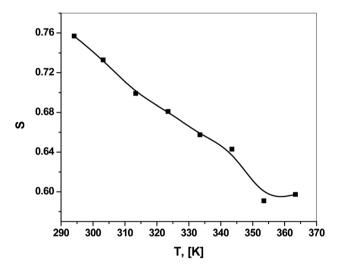


Fig. 12 Temperature dependence of the frequency exponent S.

activation of the electron drift velocity. ^{59,60} The values of $\Delta E_{\rm ac}$ were calculated from the slopes of the linear fittings. The frequency dependence plot of $\Delta E_{\rm ac}$ (Fig. 10) revealed enhanced hopping of the charge carriers between the sides of the potential barrier with increasing applied frequency. ^{59,61}

The frequency dependence of ac conductivity $\sigma_{\rm ac}$ could be explained by the following equation: $^{62-64}$

$$\sigma_{\rm ac} = {\rm constant} \times (2\pi f)^S$$

The frequency exponent S refers to the degree of interaction between the ions and their surroundings⁶⁵ and helps in identifying the conduction mechanism. $\ln \sigma_{\rm ac}$ was plotted *versus* $\ln(2\pi f)$, as shown in Fig. 11. This relation yielded a linear curve with slope S. Fig. 12 shows the temperature dependence of the frequency exponent S. The S values were less than 1 and decreased with increasing temperature over most of the studied range. Thus, ac conduction can be explained as correlated barrier hopping (CBH) between randomly distributed close pairs of centers (5–10 Å apart). This mechanism is called correlated barrier hopping between non-intimate valence alternation pairs (CBH-NVAPs) which has been explained in detail by Elliott. 19,21,55,65,666

3.4. DFT calculations

3.4.1. Geometry optimization. Fig. 13 shows the optimized structures of **PyT** and the **Ni-PyT** nanocomplex obtained using the Gaussian algorithm. For **PyT** and its nickel nanocomplex, the dipole moment values and energy factors were calculated (Table 2). The interaction of the Ni(II) ions with **PyT** in the Ni(**PyT**) nanocomplex was defined by two key parameters: the lowest unoccupied molecular orbitals (LUMOs) and the highest occupied molecular orbitals (HOMOs). Fig. 14 displays the HOMO-LOMO structure of the produced compounds. Given the higher HOMO energy of the compound, it appears to have a greater capacity to donate electrons. The larger LUMO energy indicates the increased electron-receiving capacity of the

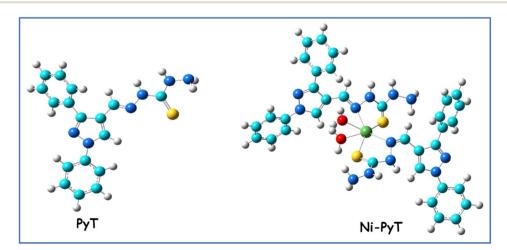


Fig. 13 Optimized structure of PyT and its Ni(PyT) nanocomplex.

Table 2 Total energy (au), energy of HOMO (eV), energy of LUMO (eV), energy gap (eV), and dipole moment (Debye) of PyT and its Ni(PyT) nanocomplex

Compound	Total energy (au)	Dipole moment (Debye)	E_{HOMO} (eV)	E_{LUMO} (eV)	$E_{\rm g}$ (eV)
PyT	-1384	6.712	-5.582	-1.783	3.797
Ni-PyT	-4429	4.940	-3.193	-2.155	1.038

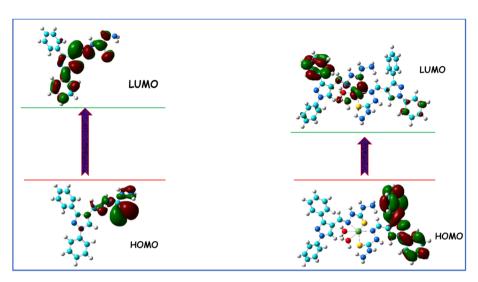


Fig. 14 E_{α} plots of PyT and its Ni(PyT) nanocomplex.

compound.⁶⁷ According to the theoretical calculations, **PyT** has higher electron donation power than Ni(II) in Ni(PyT) nanocomplex. Furthermore, the Ni(II) ion readily accepts electrons from **PyT** to create a stable Ni(PyT) nanocomplex.⁶⁷ In addition, there is a significant decrease in the energy gap from 3.797 to 1.038 eV due to the interaction of the Ni(II) ion with **PyT**. This correlates with the red shift in the absorption edge, as seen in Fig. 5. The energy gap of the Ni(PyT) nanocomplex illustrates its semiconducting behavior in the low-temperature range (294.1–333.5 K) as the ac conductivity increases with increasing temperature. This also illustrates the high value of the dielectric constant. Thus, the optical and dielectric properties of the Ni(PyT) nanocomplex show that it is a promising material for different applications.

4 Conclusion

The pyrazole thiocarbohydrazide complex of Ni(II) (Ni(PyT) was successfully synthesized. Using the TGA–DTG technique, elemental analysis, molar conductivity, UV-Vis, FT-IR, and XRD spectroscopy, as well as magnetic moment measurements, the synthesized complex was identified and verified. The Ni(PyT) complex has a nanocrystalline structure with a crystallite size of about 4.4 nm. All data reveal that the octahedral geometry of the Ni(PyT) complex is formed *via* the coordination of the N and S donor sites of the PyT ligand with the Ni(II) metal center. Increasing the frequency of the applied field reduces the dielectric loss and dielectric constant. These values increase

with increasing temperature, reaching the maximum at 323.5 K at most of the frequencies tested. Then, they decrease with increasing temperature. These properties can be explained by considering a set of dipoles and the existence of a potential barrier over which the charges must hop. This barrier decreases with increasing temperature. The results suggest that correlated barrier hopping is the mechanism of ac conduction in which hopping happens between non-intimate valence alternation pairs. The energy gap of the Ni(PyT) nanocomplex is 1.038 eV. The interaction of the Ni(II) ions with PyT leads to a redshift and decreases the energy gap from 3.797 to 1.038 eV.

Conflicts of interest

The authors declare that they do not have any conflicts of interest related to this work.

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